



Fast Recovery Epi Diodes  
Reverse Voltage - 650 Volts  
Forward Current - 80 Amperes

### Features

- High frequency operation
- High surge forward current capability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7s, per JESD 22-B106

### Mechanical data

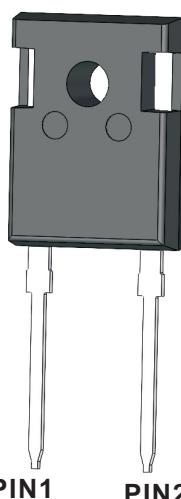
- Case: TO-247-2L
- pprox. Weight: 6.0g ( 0.21oz)
- RoHS compliant
- Case Material: "Green" molding compound, UL flammability classification 94V-0, "Halogen-free".

### Maximum Ratings And Electrical Characteristics

Ratings At 25°C Ambient Temperature Unless Otherwise Specified

Parameter	Symble	MURP8065W		Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	650		V
Maximum RMS voltage	$V_{RMS}$	460		V
Maximum DC Blocking Voltage	$V_{DC}$	650		V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	80		A
Peak Forward Surge Current,8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)(Per leg)	$I_{FSM}$	750		A
Typical Thermal Resistance (P.C.B. mounted with 3.81X3.81cm copper pad areas.)	$R_{\theta JA}$ $R_{\theta JC}$	40 0.43		°C/W
Operating Junction Temperature Range	$T_j$	-55 ~ +175		°C
Storage Temperature Range	$T_{stg}$	-55 ~ +175		°C

Parameter	Symbols	Test Conditions	Min	Typ	Max	Units
Instantaneous forward voltage per leg	$V_F$	$I_F=80A, T_J=25^{\circ}C$		1.43	1.9	V
Reverse current per leg	$I_R$	$V_R=650V, T_J=25^{\circ}C$ $V_R=650V, T_J=150^{\circ}C$		0.5	30 5	uA mA
Maximum Reverse Recovery Time	trr	$I_F=0.5A, I_R=1.0A, I_{rr}=0.25A$		70	90	ns
Maximum Reverse Recovery Time	trr	$I_F=1A, V_R=30V, DIF/Dt=200A/us$		65		ns



ROHS  
COMPLIANT

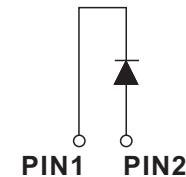
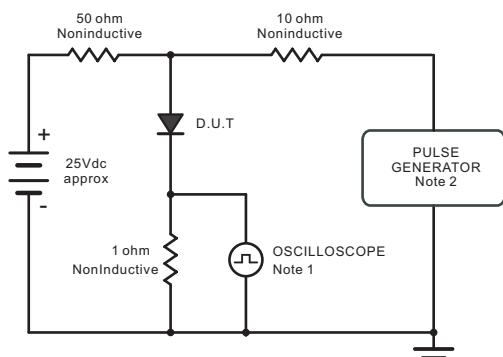




Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram



Note: 1. Rise Time = 7ns, max.  
Input Impedance = 1megohm,22pF.  
2. Ries Time =10ns, max.  
Source Impedance = 50 ohms.

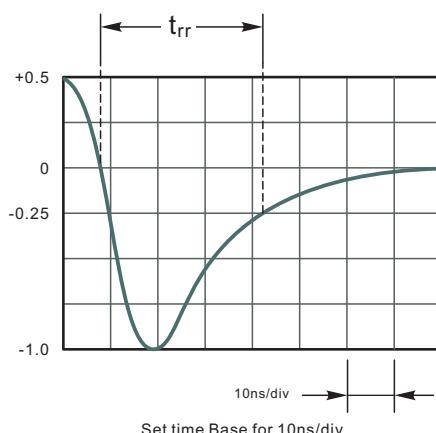


Fig.2 Forward Current Derating Curve

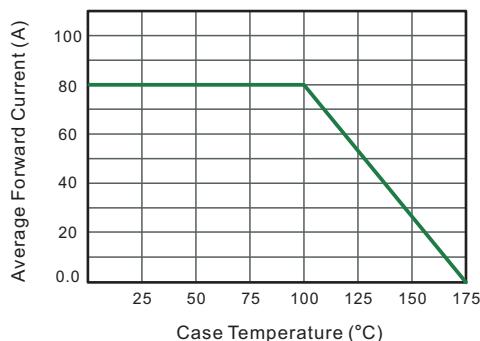


Fig.4 Typical Forward Characteristic

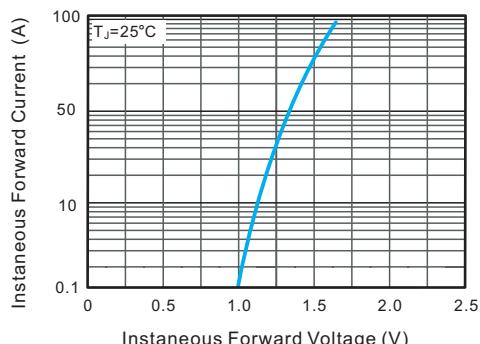


Fig.6 Max. Transient Thermal Impedance

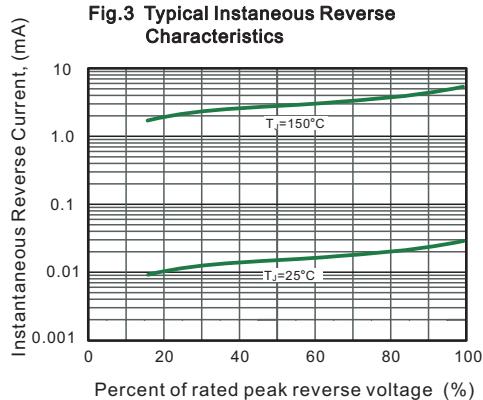
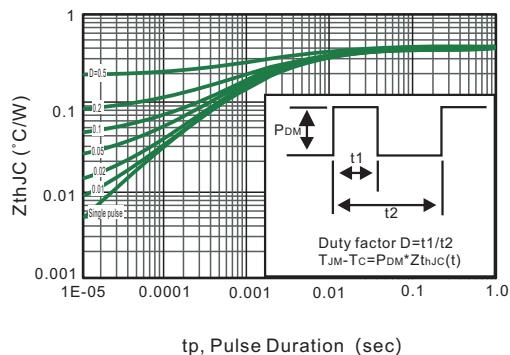


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

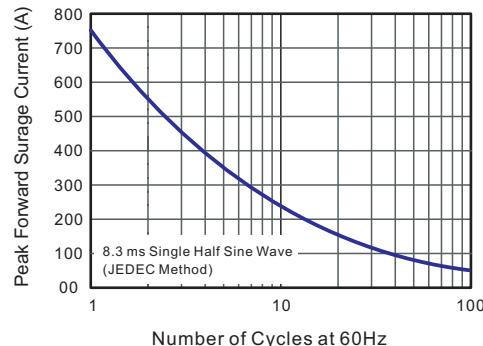
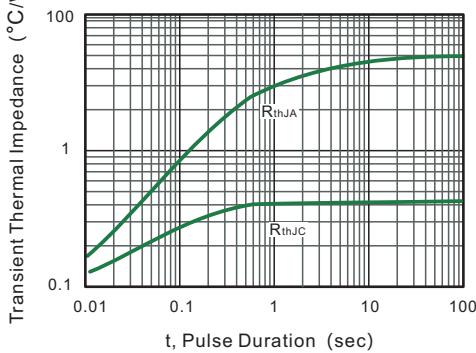


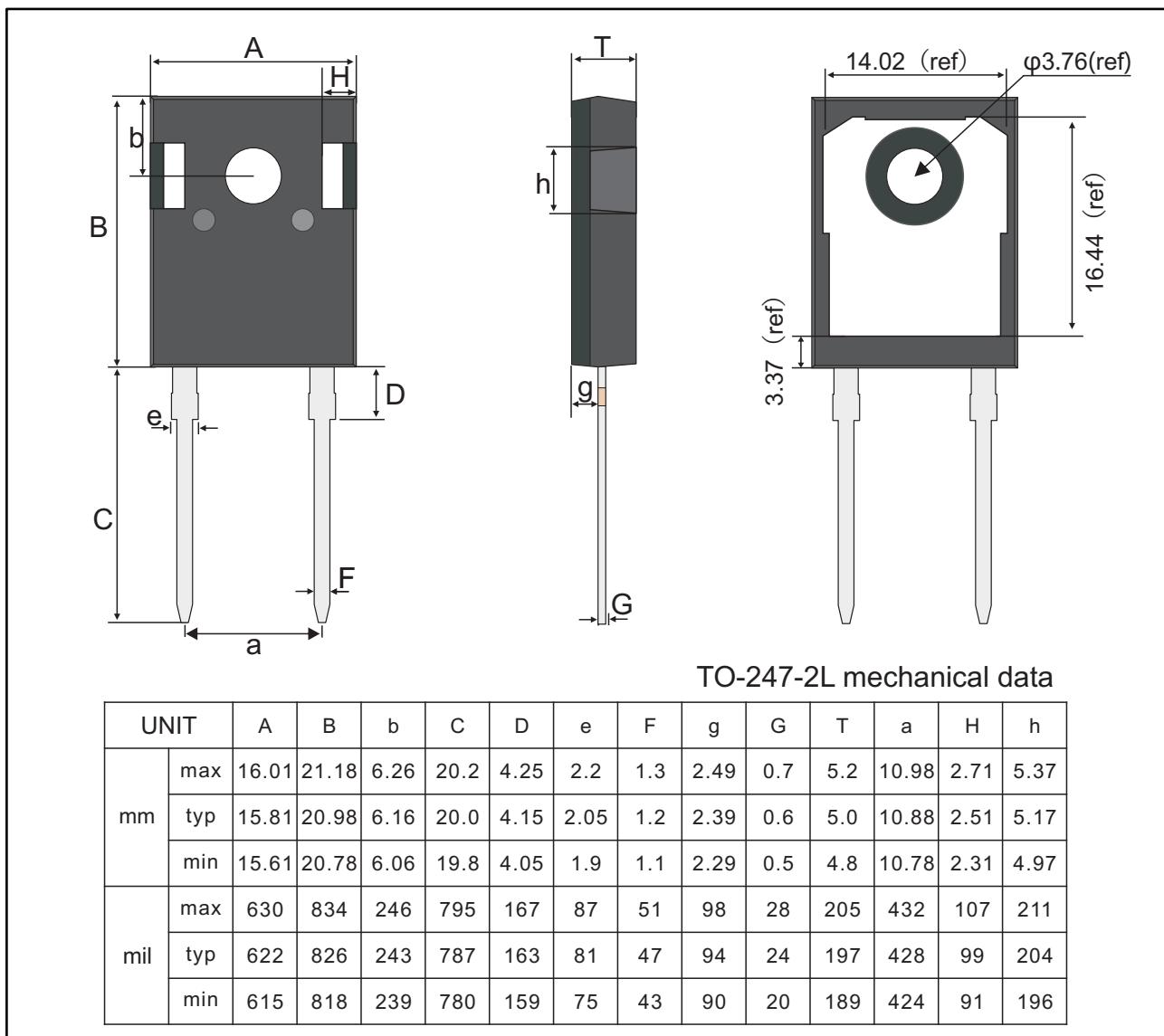
Fig.7 Typical Transient Thermal Impedance





Package Outline  
Through hole Package ; 2 leads

TO-247-2L



TO-247-2L mechanical data

UNIT		A	B	b	C	D	e	F	g	G	T	a	H	h
mm	max	16.01	21.18	6.26	20.2	4.25	2.2	1.3	2.49	0.7	5.2	10.98	2.71	5.37
	typ	15.81	20.98	6.16	20.0	4.15	2.05	1.2	2.39	0.6	5.0	10.88	2.51	5.17
	min	15.61	20.78	6.06	19.8	4.05	1.9	1.1	2.29	0.5	4.8	10.78	2.31	4.97
mil	max	630	834	246	795	167	87	51	98	28	205	432	107	211
	typ	622	826	243	787	163	81	47	94	24	197	428	99	204
	min	615	818	239	780	159	75	43	90	20	189	424	91	196

### Marking

Type number	Marking code
MURP8065W	MURP8065W



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